
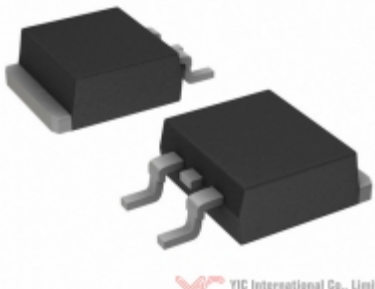


	<h2 style="color: red;">FQB4N90TM</h2>
	<p>Hersteller-Teilenummer: FQB4N90TM</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 900V 4.2A D2PAK</p> <hr/> <p>Datenblätter:  FQB4N90TM.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 32386 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB4N90TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 900V 4.2A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	32386 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 140W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	900V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	4.2A (Tc)
Rds On (Max) @ Id, Vgs	3.3 Ohm @ 2.1A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1100pF @ 25V
Verpackung	Tape & Reel (TR)



















































FQB4N90TM ist neu im Original, Suche FQB4N90TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB4N90TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB4N90TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB4P25TM Fairchild/ON Semiconductor MOSFET P-CH 250V 4A D2PAK</p>	 <p>FQB4N90TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 4.2A D2PAK</p>	 <p>FQB4P25TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 250V 4A D2PAK</p>	 <p>FQB4N90(SSW4N90A) FAIRCHILD FAIRCHILD SOT-263</p>
 <p>FQB4N80 FAIRCHILD FQB4N80 FAIRCHILD</p>	 <p>FQB4N80TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 3.9A D2PAK</p>	 <p>FQB4P40TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 400V 3.5A D2PAK</p>	 <p>FQB4N90 FSC FQB4N90 FSC</p>

heiße Teile

Mehr

 FQB3P20TM	 FQB3P20TM	 FQB3P50TM	 FQB3P50TM	 FQB44N10
 FQB44N10TM	 FQB44N10TM	 FQB46N15	 FQB46N15TM	 FQB47P06
 FQB47P06TM	 FQB4N20L	 FQB4N20LTM	 FQB4N20LTM	 FQB4N20TM
 FQB4N20TM	 FQB4N25TM	 FQB4N25TM	 FQB4N20TM	 FQB4N50TM
 FQB4N50TM	 FQB4N60C	 FQB4N80TM	 FQB4N80TM	 FQB4N90TM
 FQB4P25TM	 FQB4P25TM	 FQB50N03	 FQB50N06	 FQB50N06C
 FQB50N06L	 FQB50N06LTM	 FQB50N06LTM	 FQB50N06M	 FQB50N06TM
 FQB50N06TM	 FQB50N06TM-NL	 FQB55N06TM	 FQB55N06TM	 FQB55N10
 FQB55N10TM	 FQB55N10TM	 FQB5N20L	 FQB5N30TM	 FQB5N30TM
 FQB5N50C	 FQB5N50CF	 FQB5N50CTM	 FQB5N50CTM	 FQB5N60CTM

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